L Number	Hits	Search Text	DB	Time stamp
1	15550	emitter with (Gas or GaSe or GaTe or InS or InSe or InTe or TiS)	USPAT; US-PGPUB	2004/10/20 10:32
2	14291	(emitter with (Gas or GaSe or GaTe or InS or InSe or InTe or TiS)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:28
3	150	((emitter with (Gas or GaSe or GaTe or InS or InSe or InTe or TiS)) and @ad<20020614) and BiMOS	USPAT; US-PGPUB	2004/10/20 10:26
4	15550	emitter with ("Gas" or "GaSe" or "GaTe" or "InS" or "InSe" or "InTe" or "TiS")	USPAT; US-PGPUB	2004/10/20 10:25
5	14291	(emitter with ("Gas" or "GaSe" or "GaTe" or "InS" or "InSe" or "InTe" or "TiS")) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:26
6	150	((emitter with ("Gas" or "GaSe" or "GaTe" or "InS" or "InSe" or "InTe" or "TiS")) and @ad<20020614) and BiMOS	USPAT; US-PGPUB	2004/10/20 10:26
7	87	emitter with (III with VI)	USPAT; US-PGPUB	2004/10/20 10:35
8	69	(emitter with (III with VI)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:39
14	56	emitter with (III with VI)	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:39
15	111	emitter same (III with VI)	USPAT; US-PGPUB	2004/10/20 10:39
16	89	(emitter same (III with VI)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:49
17	0	(emitter with ("InSe")) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:50
18	1	(emitter with (In near2 Se)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:51
19	1	(emitter with (Ga near2 S)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:51
20	0	(emitter with (Ga near2 Se)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:51
21	1	(emitter with (Ga near2 Te)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:57
22	27	(emitter with (In near2 S)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:56
23	1	(emitter with (In near2 Se)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:56
24	1	(emitter with (In near2 Te)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:55
25	0	(emitter with (Tl near2 S)) and @ad<20020614	USPAT; US-PGPUB	2004/10/20 10:55
26	0	(emitter with (Tl near2 S))	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:55
27	0	(emitter with (In near2 Te))	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:56
28	0	(emitter with (In near2 Se))	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:56
29	4	(emitter with (In near2 S))	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:57
30	2	(emitter with (Ga near2 Te))	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:58
31	0	(emitter with (Ga near2 Se))	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 10:58
32	0	(emitter with (Ga near2 S))	EPO; JPO; DERWENT; IBM_TDB	2004/10/20 11:44
33	1	("20030230762").PN.	USPAT; US-PGPUB	2004/10/20 11:50
34	1	("4329625").PN.	USPAT; US-PGPUB	2004/10/20 11:50

US-PAT-NO: 3740620

DOCUMENT-IDENTIFIER: US 3740620 A

TITLE: STORAGE SYSTEM HAVING
HETEROJUNCTION-HOMOJUNCTION
                       DEVICES

---------- KWIC ---------

Detailed Description Text - DETX (14):
    It should be understood that although the method and
device described above
for forming deposit 26 used N type gallium phosphide, that
P type gallium
phosphide may also be employed if the **emitter** region 16
were N type. It should
also be noted that other **III**-V or II-**VI** compound materials
may be used in place
of the described gallium phosphide.